

**BAS70T / BAS70-04T / BAS70-05T / BAS70-06T**

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**BAS70T / BAS70-04T / BAS70-05T / BAS70-06T**

**70mA Surface Mount Small Signal Schottky Diodes- 70V**

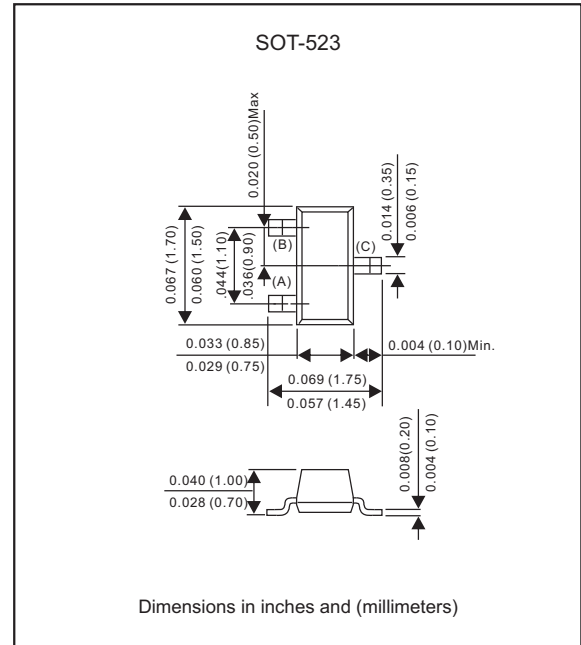
**Package outline**

**Features**

- Low current rectification and high speed switching.
- Small surface mount type.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts for green partner, exceeds environmental standards of MIL-STD-19500 /228
- High speed ( trr < 5 ns )
- Suffix "-H" indicates Halogen-free parts, ex. BAS70T-H.

**Mechanical data**

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, SOT-523
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Mounting Position : Any
- Weight : Approximated 0.003 gram



**Maximum ratings and Electrical Characteristics (AT T<sub>A</sub>=25°C unless otherwise noted)**

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Repetitive peak reverse voltage		V <sub>RRM</sub>			70	V
Reverse voltage		V <sub>R</sub>			70	V
Non-Repetitive Peak Forward Surge Current	@ t = 1.0s	I <sub>FSM</sub>			100	mA
Forward continuous current		I <sub>FM</sub>			70	mA
Power dissipation		P <sub>D</sub>			150	mW
Thermal Resistance	Junction to Ambient	R <sub>θJA</sub>		667		°C/W
Junction temperature		T <sub>J</sub>	-55		+125	°C
Storage temperature		T <sub>STG</sub>	-55		+125	°C
Forward voltage	I <sub>F</sub> = 1 mA	V <sub>F</sub>			0.41	V
	I <sub>F</sub> = 15 mA	V <sub>F</sub>			1.0	V
Reverse current	V <sub>R</sub> = 50 V	I <sub>R</sub>			0.1	uA
Diode capacitance	V <sub>R</sub> = 0 V, f = 1MHz	C <sub>T</sub>			2.0	pF
Reverse recovery time	I <sub>F</sub> = I <sub>F</sub> =10 mA, I <sub>RR</sub> = 0.1 X I <sub>R</sub> , R <sub>L</sub> =100 <sub>OHM</sub>	t <sub>rr</sub>			5	ns

Rating and characteristic curves for each diode (BAS70T / BAS70-04T / BAS70-05T / BAS70-06T)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

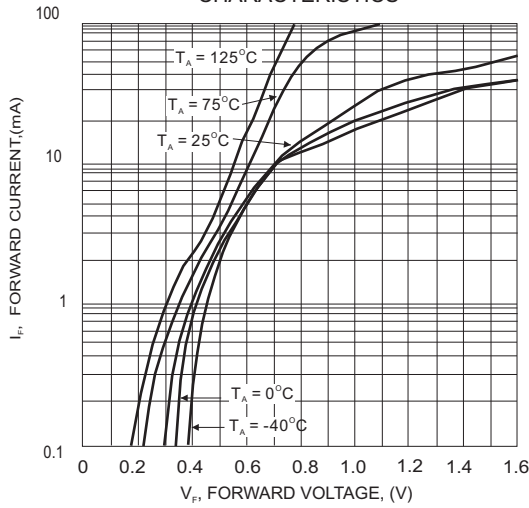


FIG.2 - TYPICAL REVERSE CHARACTERISTICS

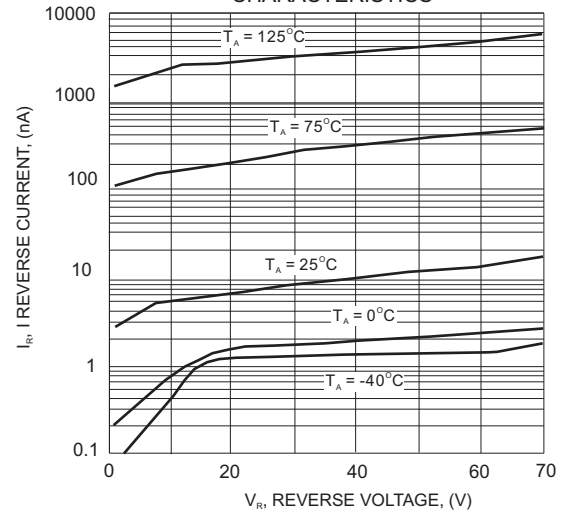


FIG.3-TYPICAL JUNCTION CAPACITANCE

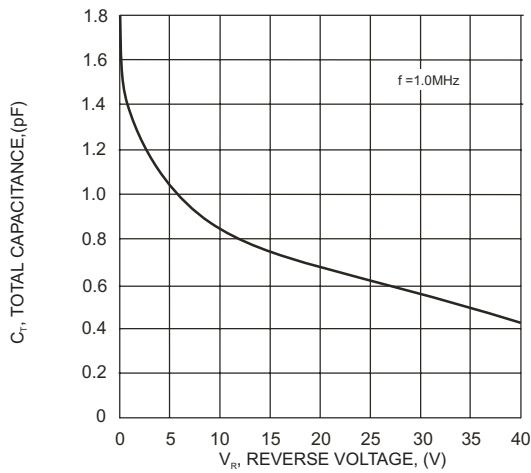
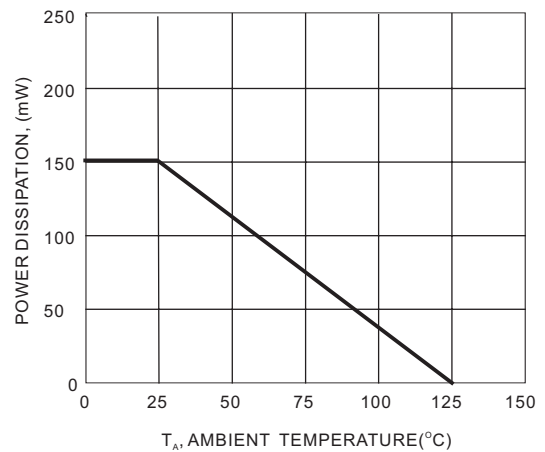
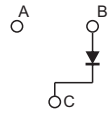
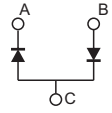
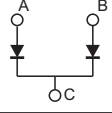
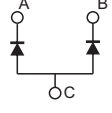


Fig. 4 POWER DERATING CURVE



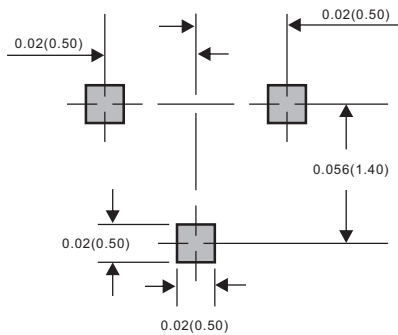
**BAS70T / BAS70-04T / BAS70-05T / BAS70-06T**

**Pinning information**

Type number	Marking code	Symbol
BAS70T	7C	
BAS70-04T	7D	
BAS70-05T	7E	
BAS70-06T	7F	

**Suggested solder pad layout**

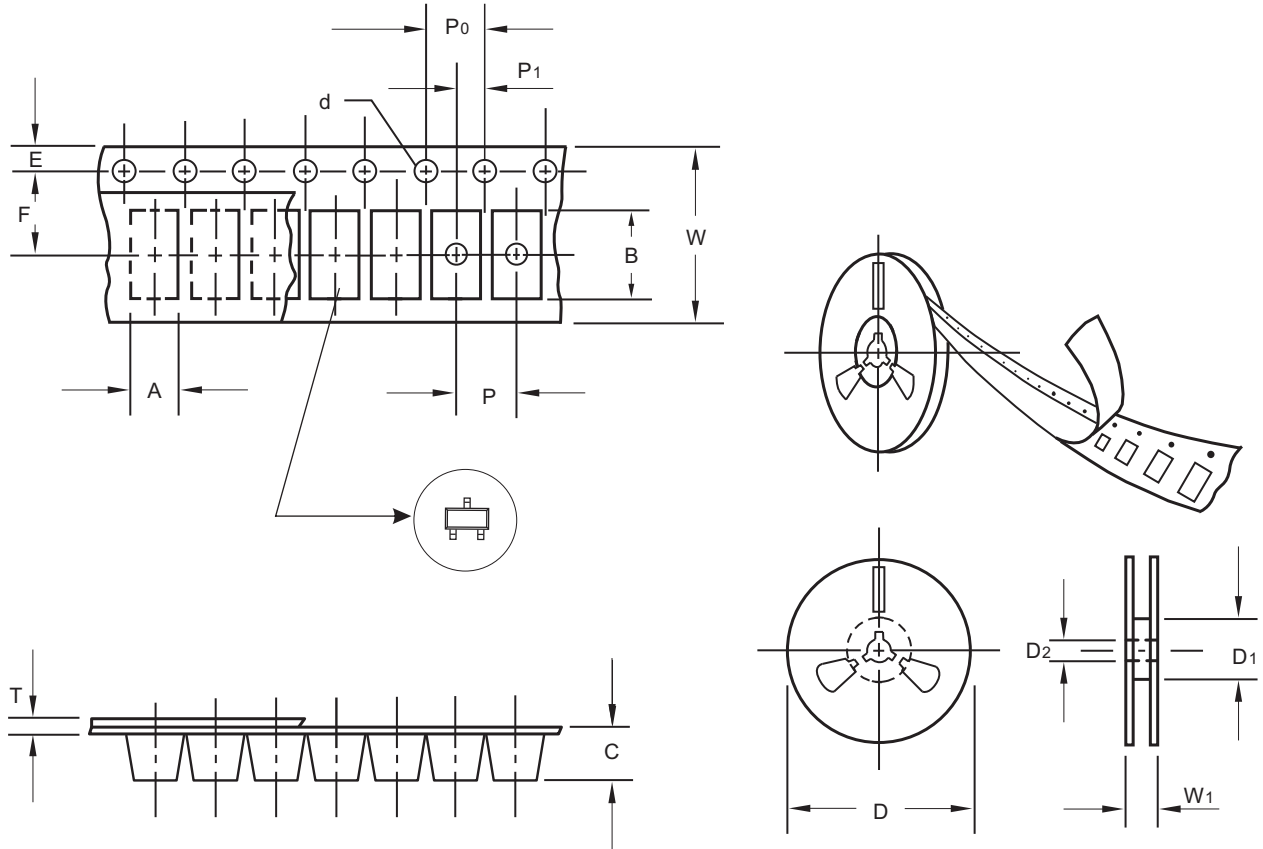
SOT-523



Dimensions in inches and (millimeters)

**BAS70T / BAS70-04T / BAS70-05T / BAS70-06T**

**Packing information**



unit:mm

Item	Symbol	Tolerance	SOT-523
Carrier width	A	0.1	1.73
Carrier length	B	0.1	1.85
Carrier depth	C	0.1	0.90
Sprocket hole	d	0.1	1.5
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	60.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W1	1.0	11.40

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

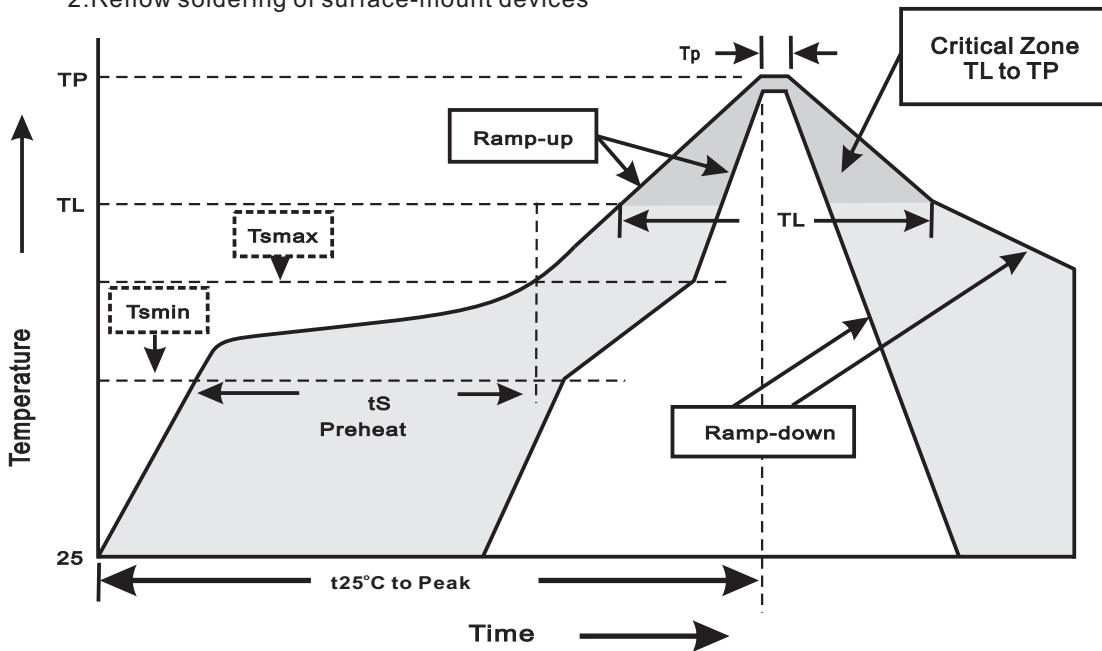
**BAS70T / BAS70-04T / BAS70-05T / BAS70-06T**

**Reel packing**

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOT-523	7"	3,000	4.0	30,000	183*183*123	178	382*262*387	240,000	11.6

**Suggested thermal profiles for soldering processes**

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T <sub>L</sub> to T <sub>P</sub> )	<3°C/sec
Preheat -Temperature Min(T <sub>smmin</sub> ) -Temperature Max(T <sub>smmax</sub> ) -Time(min to max)(t <sub>s</sub> )	150°C 200°C 60~120sec
T <sub>smmax</sub> to T <sub>L</sub> -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T <sub>L</sub> ) -Time(t <sub>L</sub> )	217°C 60~260sec
Peak Temperature(T <sub>P</sub> )	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t <sub>P</sub> )	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

**BAS70T / BAS70-04T / BAS70-05T / BAS70-06T****High reliability test capabilities**

Item Test	Conditions	Reference
1. Solder Resistance	at 260±5°C for 10±2sec. immerse body into solder 1/16"±1/32"	MIL-STD-750D METHOD-2031
2. Solderability	at 245±5°C for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_R=80\%$ rate at $T_J=125^\circ\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at $T_A=25^\circ\text{C}$ for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^\circ\text{C}$ , $I_F = I_O$ On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	$15P_{SIG}$ at $T_A=121^\circ\text{C}$ for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to +125°C dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Thermal Shock	0°C for 5 min. rise to 100°C for 5 min. total 10 cycles.	MIL-STD-750D METHOD-1056
9. Forward Surge	Non-Repetitive Peak Forward Surge Current $t = 1.0s$	MIL-STD-750D METHOD-4066-2
10. Humidity	at $T_A=85^\circ\text{C}$ , RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
11. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031